

SANYO Semiconductors

DATA SHEET

An ON Semiconductor Company

LV8405V — ^{Bi-CMOS IC} 2ch Forward/Reverse Motor Driver

Overview

LV8405T is a 2ch forward/reverse motor driver IC using D-MOS FET for output stage. As MOS circuit is used, it supports the PWM input. Its features are that the on resistance $(0.75\Omega \text{ typ})$ and current dissipation are low.

It also provides protection functions such as heat protection circuit and reduced voltage detection and is optimal for the motors that need high-current.

Functions

- 2ch forward/reverse motor driver.
- Low power consumption.
- Low ON resistance 0.75Ω .

- Built-in low voltage reset and thermal shutdown circuit.
- Four mode function forward/reverse, brake, stop.
- Built-in charge pump.

Specifications

Maximum Ratings at $Ta = 25^{\circ}C$, SGND = PGND = 0V

Parameter	Symbol	Conditions	Ratings	Unit
Power supply voltage (for load)	VM max		-0.5 to 16.0	V
Power supply voltage (for control)	V _{CC} max		-0.5 to 6.0	V
Output current	I _O max		1.4	А
Output peak current	I _O peak	$t \leq 10ms$	2.5	А
Input voltage	V _{IN} max		-0.5 to V _{CC} +0.5	V
Allowable power dissipation	Pd max	Mounted on a specified board*	800	mW
Operating temperature	Topr		-30 to +85	°C
Storage temperature	Tstg		-55 to +150	°C

* Specified board : 114.3mm × 76.1mm × 1.6mm, glass epoxy board.

Caution 1) Absolute maximum ratings represent the value which cannot be exceeded for any length of time.

Caution 2) Even when the device is used within the range of absolute maximum ratings, as a result of continuous usage under high temperature, high current, high voltage, or drastic temperature change, the reliability of the IC may be degraded. Please contact us for the further details.

- Any and all SANYO Semiconductor Co.,Ltd. products described or contained herein are, with regard to "standard application", intended for the use as general electronics equipment. The products mentioned herein shall not be intended for use for any "special application" (medical equipment whose purpose is to sustain life, aerospace instrument, nuclear control device, burning appliances, transportation machine, traffic signal system, safety equipment etc.) that shall require extremely high level of reliability and can directly threaten human lives in case of failure or malfunction of the product or may cause harm to human bodies, nor shall they grant any guarantee thereof. If you should intend to use our products for new introduction or other application different from current conditions on the usage of automotive device, communication device, office equipment, industrial equipment etc. , please consult with us about usage condition (temperature, operation time etc.) prior to the intended use. If there is no consultation or inquiry before the intended use, our customer shall be solely responsible for the use.
- Specifications of any and all SANYO Semiconductor Co.,Ltd. products described or contained herein stipulate the performance, characteristics, and functions of the described products in the independent state, and are not guarantees of the performance, characteristics, and functions of the described products as mounted in the customer's products or equipment. To verify symptoms and states that cannot be evaluated in an independent device, the customer should always evaluate and test devices mounted in the customer's products or equipment.

SANYO Semiconductor Co., Ltd. http://semicon.sanyo.com/en/network

71812 SY/D1411 SY 20111205-S00003/33110 SY 20100317-S00001 / N1908 MS 20081104-S00002 / O2208 MS PC 20081002-S00002 No.A1340-1/6

Allowable Operating Conditions at Ta = 25°C, SGND = PGND = 0V

Parameter	Symbol	Conditions	Ratings	Unit
Power supply voltage (VM pin)	VM		1.5 to 15.0	V
Power supply voltage (V _{CC} pin)	VCC		2.8 to 5.5	V
Input signal voltage	VIN		0 to V _{CC}	V
Input signal frequency	f max		200	kHz

Electrical Characteristics Ta = 25° C, V_{CC} = 3.0V, VM = 6.0V, SGND = PGND = 0V, unless otherwise specified.

Parameter		0				Ratings		Unit
		Symbol	Conditions Remarks		min	typ	max	Unit
Standby load current drain		IMO	$V_{CC} = 0V, VM = 6V$	1			1.0	μΑ
Operating contr	ol current drain	IC1	When V_{CC} is applied, with no load	2		0.85	1.2	mA
High-level input	voltage	VIH	$2.7 \leq V_{CC} \leq 5.5 V$		0.6×V _{CC}		VCC	V
Low-level input	voltage	VIL	$2.7 \leq V_{CC} \leq 5.5 V$		0		0.2×V _{CC}	V
High-level input current (IN1, IN2, IN3, IN4)		IIH	IN1, IN2, IN3, IN4 = 3V	3		15	25	μΑ
Low-level input current (IN1, IN2, IN3, IN4)		IIL	IN1, IN2, IN3, IN4 = 0V	3	-1.0			μΑ
Pull-down resistance value (IN1-4)		RPD1			100	200	400	kΩ
Charge pump voltage		VG	V _{CC} + VM		8.5	9.0	9.5	V
Output ON resistance 1		RON1	Sum of top and bottom sides ON resistance.	4		0.75	1.2	Ω
Output ON resistance 2		RON2	Sum of top and bottom sides ON resistance. $V_{CC} = 2.8V$	4		1.0	1.5	Ω
Low-voltage detection voltage		VCS	V _{CC} pin voltage is monitored	5	2.15	2.30	2.45	V
Thermal shutdown temperature		Tth	Design guarantee value *	6	150	180	210	°C
Output block	Turn-on time	TPLH		7		0.2	0.4	μS
	Turn-off time	TPHL		7		0.2	0.4	μS

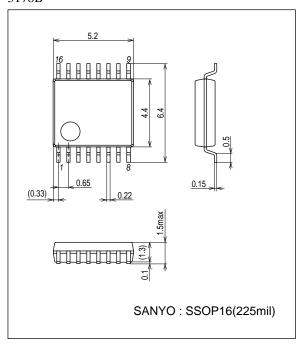
* : Design guarantee value and no measurement is preformed.

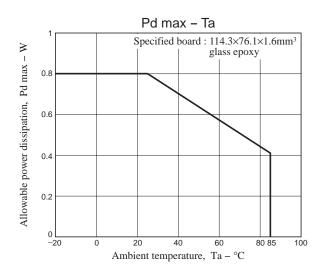
Remarks

- 1. Current consumption when output at the VM pin is off.
- 2. Current consumption at the V_{CC} pin when V_{CC} is 3V and IN1 to IN4 are all 0V (standby mode).
- 3. Pins IN 1, 2, 3, and 4 are all pulled down.
- 4. Sum of upper and lower saturation voltages of OUT pin divided by the current.
- 5. All power transistors are turned off if a low V_{CC} condition is detected.
- 6. All output transistors are turned off if the thermal protection circuit is activated. They are turned on again as the temperature goes down.
- 7. Rising time from 10 to 90% and falling time from 90 to 10% are specified.

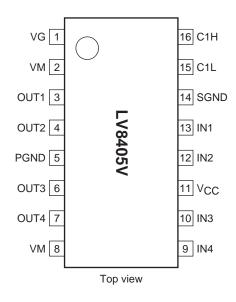
Package Dimensions

unit : mm (typ) 3178B

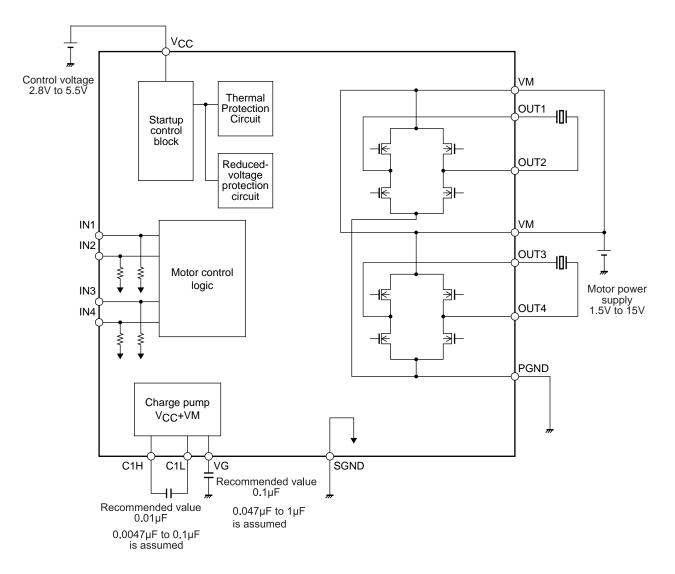




Pin Assignment



Block Diagram



* Connect a kickback absorption capacitor as near as possible to the IC. Coil kickback may cause increase in VM line voltage, and a voltage exceeding the maximum rating may be applied momentarily to the IC, which results in deterioration or damage of the IC

Truth Table

IN1 (IN3)	IN2 (IN4)	OUT1 (OUT3)	OUT2 (OUT4)	Charge pump	Mode
н	Н	Z	Z	ON	Standby
н	L	L	н		Reverse
L	Н	н	L		Forward
L	L	L	L		Brake

- : denotes a don't care value. Z : High-impedance

 \bullet The charge pump is always activated as long as $V_{\mbox{CC}}$ is applied.

* All power transistors turn off and the motor stops driving when the IC is detected in low voltage or thermal protection mode.

<mark>in F</mark> ur	octions		
Pin No.	Pin name	Description	Equivalent circuit
16 1	C1H VG	Step-up capacitor connection pin.	C1H
13	IN1	Driver output switching.	V _{CC}
12	IN2	(Pull-down resistor incorporated)	
10	IN3		
9	IN4		→ → → → → → → → → → → → → → → → → → →
3 4 7	OUT1 OUT2 OUT3 OUT4	Driver output.	
2	VM	Motor block power supply.	PGND
8 11	V.c	Logic block power supply.	
11	V _{CC} SGND	Control block ground.	
5	PGND	Driver block ground.	

- SANYO Semiconductor Co.,Ltd. assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all SANYO Semiconductor Co.,Ltd. products described or contained herein.
- Regarding monolithic semiconductors, if you should intend to use this IC continuously under high temperature, high current, high voltage, or drastic temperature change, even if it is used within the range of absolute maximum ratings or operating conditions, there is a possibility of decrease reliability. Please contact us for a confirmation.
- SANYO Semiconductor Co.,Ltd. strives to supply high-quality high-reliability products, however, any and all semiconductor products fail or malfunction with some probability. It is possible that these probabilistic failures or malfunction could give rise to accidents or events that could endanger human lives, trouble that could give rise to smoke or fire, or accidents that could cause damage to other property. When designing equipment, adopt safety measures so that these kinds of accidents or events cannot occur. Such measures include but are not limited to protective circuits and error prevention circuits for safe design, redundant design, and structural design.
- In the event that any or all SANYO Semiconductor Co.,Ltd. products described or contained herein are controlled under any of applicable local export control laws and regulations, such products may require the export license from the authorities concerned in accordance with the above law.
- No part of this publication may be reproduced or transmitted in any form or by any means, electronic or mechanical, including photocopying and recording, or any information storage or retrieval system, or otherwise, without the prior written consent of SANYO Semiconductor Co.,Ltd.
- Any and all information described or contained herein are subject to change without notice due to product/technology improvement, etc. When designing equipment, refer to the "Delivery Specification" for the SANYO Semiconductor Co.,Ltd. product that you intend to use.
- Upon using the technical information or products described herein, neither warranty nor license shall be granted with regard to intellectual property rights or any other rights of SANYO Semiconductor Co.,Ltd. or any third party. SANYO Semiconductor Co.,Ltd. shall not be liable for any claim or suits with regard to a third party's intellectual property rights which has resulted from the use of the technical information and products mentioned above.

This catalog provides information as of July, 2012. Specifications and information herein are subject to change without notice.